PCN Number: 2023			230328000.1			PCN Date: March 30, 202		March 30, 2023			
Title	e:	-				site (RFAB) using q			Techno	ogy, Die Revision,	
		and additiona	I ASS	em	nbiy	site options for sel	<u>ect devices</u>				
Cus	tomer	Contact:	<u> </u>	PCN	N M	<u>anager</u>	Dept:		Q	uality Services	
Proposed 1 st Ship Date:			Jun 28, 2023 Sample re accepted		· I Ann		oril 28, 2023*				
*Sa	mple i	requests rece	ived	af	fteı	r April 28, 2023 w	ill not be s	upp	orted.		
Cha	nge Ty	/pe:									
\boxtimes	Assen	nbly Site				Assembly Process			Assembly Materials		
\boxtimes	Desig	n				Electrical Specification			Mechar	nical Specification	
☐ Test Site				A	Packing/Shipping/Labeling			Test Pr	ocess		
☐ Wafer Bump Site					Wafer Bump Material			Wafer Bump Process			
□ Wafer Fab Site				☑ Wafer Fab Materials			\boxtimes	Wafer I	Fab Process		
·				☐ Part number change							
	PCN Details										

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (RFAB, LBC9) and additional Assembly site (PHI, MLA) for selected devices listed below in the product affected section.

C	urrent Fab Site		Additional Fab Site			
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter	
DL-LIN	VIP	150 mm				
SFAB	JI1	150 mm	RFAB	LBC9	300 mm	
DL-LIN	LINCMOS	150 mm				

The die was also changed as a result of the process change.

Construction Differences are as follows:

Group 1 Devices (RFAB as an additional Fab site & TIEMA/LEN adding PHI as an additional Assembly site):

	TIEMA	LEN	TIPI
Mount Compound	8075531	SID#0003C10332	8095733
Mold Compound	8097131	SID#0011G60007	4222198
Bond wire composition, diameter	Cu, 0.96 mil	Au, 1.0 mil	Cu, 0.8 mil
Lead Finish	Matte Sn	NiPdAu	NiPdAu

Group 2 Devices (RFAB as an additional Fab site & FMX/TAI adding MLA as an additional Assembly site):

	FMX	MLA
Mount Compound	4147858	4147858
Mold Compound	4211880	4211880
Bond wire composition, diameter	Cu, 0.96 mil	Cu, 0.8 mil

Group 3 Devices (RFAB as an additional Fab site & TAI adding MLA as an additional Assembly site):

	TAI	MLA
Bond wire composition, diameter	Cu, 0.96 mil	Cu, 0.8 mil

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474	
☑ No Change	⊠ No Change	⊠ No Change	☑ No Change	

Changes to product identification resulting from this PCN:

Fab Site Information:

. 45 5116 2111 5111 4115111				
Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City	
DL-LIN	DLN	USA	Dallas	
SH-BIP-1	SHE	USA	Sherman	
RFAB	RFB	USA	Richardson	

Die Rev:

Current	New			
Die Rev [2P]	Die Rev [2P]			
B, C	A			

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TIEM	CU6	MYS	Mela ka
LEN	LIN	TWN	Taichung
FMX	MEX	MEX	Aguascalientes
TAI	TAI	TWN	Chung Ho, New Taipei City
TIPI	PHI	PHL	Baguio City MLA
MLA	MLA	MYS	Kuala Lumpur

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20;

MADE IN: Malaysia 2DC: 2Q: MSL '2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

LBL: 5A (L)TO:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812

(2P) REV: (V) 9933317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

Grou	p 1	Device	List	(RFAB	as ac	dditiona	l Fab	site &	PHI a	as an	additional	Assembly	site)) :
------	------------	---------------	------	-------	-------	----------	-------	--------	-------	-------	------------	-----------------	-------	------------

LM7301IM5	LM7301IM5X/NOPB	LM7301IM5X/S7000823	TLV2231IDBVR
LM7301IM5/NOPB	LM7301IM5X/S5000655	LM7341MFX/NOPB	TLV2731IDBVR
LM7301IM5X			

Group 2 Device List (RFAB as additional Fab site & MLA as an additional Assembly site):

TLC277CDR TLC277IDR

Group 3 Device List (RFAB as additional Fab site & MLA as an additional Assembly site):

TLC279CDR TLC279IDR

For alternate parts with similar or improved performance, please visit the product page on TI.com

Qualification Report

Approve Date 28-Jul-2020

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: OPA991IDBVR	QBS Process Reference: <u>OPA4990IDR</u>	QBS Package Reference: <u>OPA990IDBVR</u>
PC	PreCon Level 1	Level 1-260C	-	-	6/933/0
PC	PreCon Level 2	Level 2-260C	-	3/1477/1 (1)	3/246/0
ED	Electrical Characterization	Per Datasheet Parameters	3/90/0	3/90/0	3/90/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	6/462/0
AC	Autoclave 121C	96 Hours	-	3/231/5 (2)	1/77/0
AC	Autoclave 121C	96 hours	-	-	2/154/0
тс	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0	3/231/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0
HTSL	High Temp Storage Bake 175C	500 Hours	-	3/231/0	-
HTOL	Life Test, 150C	300 Hours	-	3/231/10 (3)	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	1/800/0	-
нвм	ESD - HBM	2500 V	1/3/0	-	-
нвм	ESD - HBM	3000 V	-	3/9/0	-
CDM	ESD - CDM	1500 V	3/9/0	2/6/0	3/9/0
LI	Lead Pull to Destruction	Leads	-	1/24/0	-
LU	Latch-up	Per JESD78	3/18/0	3/18/0	3/18/0
MSL	Automotive Moist Sens. L2	Level 2-260C	-	3/36/0	-
MSL	Moisture Sensitivity	Level 1-260C	-	-	3/36/0

Туре	Test Name / Condition	Duration	Qual Device: OPA991IDBVR	QBS Process Reference: <u>OPA4990IDR</u>	QBS Package Reference: <u>OPA990IDBVR</u>
WBP	Bond Pull	Wires	1/76/0	3/228/0	3/228/0
WBS	Ball Bond Shear	Wires	1/76/0	3/288/0	3/228/0

- QBS: Qual By Similarity
- Qual Device OPA991IDBVR is qualified at LEVEL1-260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:
Qualified Pb-Free(SMT) and Green
NOTE (1): T0 failing units got mixed back in with passing ones for the post-stress test resulting in false fails. See 8D attached to the eQDB
NOTE (2): Fails were due to mechanical damage from mishandling at test. Discounted.
NOTE (3): Fails due to faulty BI sockets. See 8D attached to the eQDB.

Qualification Report

Approve Date 21-May-2021

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: OPA2991IDR	QBS Product Reference: <u>OPA2991IDR</u>	QBS Process Reference: <u>OPA4990IDR</u>	QBS Package Reference: <u>OPA2990IDR</u>
PC	PreCon Level 1	Level 1-260C	1/160/0	-	-	-
PC	PreCon Level 2	Level 2-260C	-	-	3/1477/0	3/990/0
ED	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	3/90/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	3/231/0
AC	Autoclave 121C	96 Hours	1/77/0	-	3/231/0	-
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	-	-	3/231/0
тс	Temperature Cycle, -65/150C	500 Cycles	1/77/0	-	3/231/0	3/231/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	-	3/231/0
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	3/231/0	-
HTOL	Life Test, 150C	300 Hours	-	-	3/231/10 (1)	3/231/0
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	1/800/0	-
нвм	ESD - HBM	2500 V	-	1/3/0	-	-
нвм	ESD - HBM	3000 V	-	-	3/9/0	3/9/0
CDM	ESD - CDM	1500 V	-	1/3/0	2/6/0	3/9/0
LU	Latch-up	Per JESD78	-	1/6/0	3/18/0	6/36/0
MSL	Moisture Sensitivity, L2	Level 2-260C	-	1/12/0	3/36/0	-

	Туре	Test Name / Condition	Duration	Qual Device: OPA2991IDR	QBS Product Reference: OPA2991IDR	QBS Process Reference: OPA4990IDR	QBS Package Reference: OPA2990IDR
	WBP	Bond Pull	Wires	-	1/76/0	3/228/0	3/228/0
ſ	WBS	Ball Bond Shear	Wires	-	1/76/0	3/228/0	3/228/0

⁻ QBS: Qual By Similarity

- Qual Device OPA2991IDR is qualified at LEVEL1-260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green
NOTE (1): Fails due to faulty BI sockets. See 8D attached to the eQDB.

Qualification Report Approve Date 21-May-2021

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: OPA4991IDR	QBS Product Reference: <u>OPA4991IDR</u>	QBS Process / Package Reference: <u>OPA4990IDR</u>
PC	PreCon Level 1	Level 1-260C	1/80/0	-	-
PC	PreCon Level 2	Level 2-260C	-	1/166/0	3/1477/0
ED	Electrical Characterization	Per Datasheet Parameters	-	3/90/0	3/90/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0
AC	Autoclave 121C	96 Hours	1/77/0	1/77/0	3/231/0
тс	Temperature Cycle, -65/150C	500 Cycles	1/77/0	1/77/0	3/231/0
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	3/231/0
HTOL	Life Test, 150C	300 Hours	-	1/77/0	3/231/10 (1)
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	1/800/0
нвм	ESD - HBM	4000 V	-	3/9/0	-
нвм	ESD - HBM	3000 V	-	-	3/9/0
CDM	ESD - CDM	1500 V	-	3/9/0	2/6/0
LU	Latch-up	Per JESD78	-	3/18/0	3/18/0
MSL	Moisture Sensitivity, L1	Level 1-260C	1/12/0	-	-
MSL	Moisture Sensitivity, L2	Level 2-260C	-	1/12/0	3/36/0
WBP	Bond Pull	Wires	-	1/76/0	3/228/0
WBS	Ball Bond Shear	Wires	-	1/76/0	3/228/0

- QBS: Qual By Similarity
- Qual Device OPA4991IDR is qualified at LEVEL2-260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours are equivalent HTSL options based on a constant HTSL options are equivalent HTSL options are equ
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

NOTE (1): Fails due to faulty BI sockets. See 8D attached to the eQDB

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail			
WW Change Management Team	PCN www admin_team@list.ti.com			

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